

DESCRIPTION

The transient voltage suppressor (TVS) diode is designed for asymmetrical (12V to -7V) protection in multi-point data transmission standard RS-485 applications.

be used to protect devices from transient voltages resulting from electrostatic discharge (ESD), electrical fast transients (FET), and lightning.

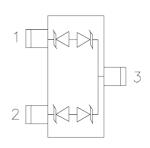
The features 400 Watts (tp=8/20µs) of power handling capability to accommodate the higher transient voltage levels which may be expected in extended common mode applications. This provides higher equipment reliability and eliminates the "guess work" required when using zener diodes that are not rated to handle such transient conditions.

The integrated design aids in reducing voltage over-shoot associated with trace inductance. The low clamping voltage of the minimizes the stress on the protected transceiver. The SOT-23 package allows flexibility in the design of "crowed" circuit boards.

ORDERING INFORMATION

◆ Package: SOT-23
◆ Marking: 712 or C72
◆ Material: Halogen free
◆ Packing: Tape & Reel
Quantity per reel: 3,000pcs

PIN CONFIGURATION & SCHEMATIC



SOT23 (Top View)

FEATURES

- ♦400 watts peak pulse power (tp=8/20µs)
- ♦ Transient protection for asymmetrical data lines to IEC 61000-4-2 (ESD) ±15kV(air), ±8kV(contact) IEC 61000-4-4 (FET) 40A (5/50ns) IEC 61000-4-5 (Lightning) 12A (8/20µs)
- ♦Protects two +12V to -7V lines
- ♦Low capacitance
- ♦Low leakage current
- ♦Low clamping voltage
- ♦ Solid-state silicon avalanche technology
- ♦RoHS compliant

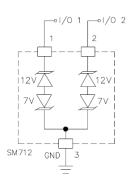
MACHANICAL DATA

- ♦SOT-23 package
- ♦ Terminal: Matte tin plated.
- ♦ Packaging: Tape and Reel
- ♦ High temperature soldering guaranted:260 °C/10s
- ♦Reel size: 7 inch

APPLICATIONS

- ♦Protection of RS-485 transceivers with extended common-mode range
- ♦ Security systems
- ♦ Automatic Teller Machines
- ♦HFC systems
- ♦Networks

CIRCUIT DIAGRAM





ABSOLUTE MAXIMUM RATING									
Symbol	Parameter	Value	Units						
P _{PP}	Peak Pulse Power (8/20µs)	400	W						
I _{PP}	Peak Pulse Current (8/20µs)	17	Α						
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV						
T _{OPT}	Operating Temperature	-55/+150	°C						
T _{STG}	Storage Temperature	-55/+150	°C						

ELECTRICAL CHARACTERISTICS (Tamb=25°C)											
Symbol	Parameter	Test Condition	Pin 1 to 3 and Pin 2 to 3			Pin 3 to 1 and Pin 3 to 2			Units		
			Min	Тур	Max	Min	Тур	Max			
V _{RWM}	Reverse Working Voltage	Pin 3 to 1 or Pin 2 to 1			12			7	V		
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA	13.3			7.5			V		
I _R	Reverse Leakage Current	$V_R = V_{RWM}$			1			20	μΑ		
V _{C1}	Clamping Voltage 1	$I_{PP} = 5A,$ $t_p = 8/20 \mu s$			20			10	V		
V _{C2}	Clamping Voltage 2	$I_{PP} = 17A,$ $t_p = 8/20 \mu s$			26			12	٧		
C _{J1}	Junction Capacitance 1	V _R = 0V, f = 1MHz			75			75	pF		
C _{J2}	Junction Capacitance 2	$V_R = V_{RWM}$, $f = 1MHz$		45			45		pF		

